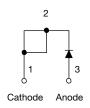


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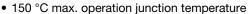
Fast Soft Recovery Rectifier Diode, 20 A

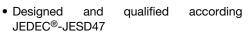




PRODUCT SUMMARY				
Package	TO-220FP			
I _{F(AV)}	20 A			
V_{R}	1000 V, 1200 V			
V _F at I _F	1.31 V			
I _{FSM}	320 A			
t _{rr}	95 ns			
T _J max.	150 °C			
Diode variation	Single die			
Snap factor	0.6			

FEATURES







• UL E78996 approved

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





HALOGEN FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-20ETF...FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V _{RRM}		1000 to 1200	V			
I _{F(AV)}	Sinusoidal waveform	20	^			
I _{FSM}		320	A			
t _{rr}	1 A, 100 A/μs	95	ns			
V _F	20 A, T _J = 25 °C	1.31	V			
T _J	Range	-40 to 150	°C			

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-20ETF10FPPbF, VS-20ETF10FP-M3	1000	1100	6		
VS-20ETF12FPPbF, VS-20ETF12FP-M3	1200	1300	O		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 50 °C, 180° conduction half sine wave	20	
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	270	Α
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	320	
Maximum I ² t for fusing I ² t	12+	10 ms sine pulse, rated V _{RRM} applied	365	- A ² s
	10 ms sine pulse, no voltage reapplied	515	A-S	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied 5150 A		A²√s



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	20 A, T _J = 25 °C		1.31	V
Forward slope resistance	r _t	T _{.I} = 150 °C	11.88	mΩ	
Threshold voltage	V _{F(TO)}	1J = 150 C	0.93	V	
Maximum reverse leakage current	I	T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA
Maximum reverse leakage current	I _{RM}	T _{.1} = 150 °C		6	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	I _F at 20 Apk	400	ns	I _{FM} t
Reverse recovery current	I _{rr}	25 A/μs	6.1	А	$t_a \mid t_b$
Reverse recovery charge	Q _{rr}	25 °C	1.7	μC	dir/Q _{rr}
Snap factor	S	Typical	0.6		I _{RM(REC)}

THERMAL - MECH	THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	rage	T _J , T _{Stg}		-40 to 150	°C
Maximum thermal resistan junction to case	ce,	R_{thJC}	DC operation	2.5	
Maximum thermal resistan junction to ambient	ce,	R_{thJA}		62	°C/W
Typical thermal resistance case to heatsink	,	R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	OZ.
minimum				6 (5)	kgf · cm
Mounting torque maxim	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-220 FULL-PAK	20ETF10FP 20ETF12FP	

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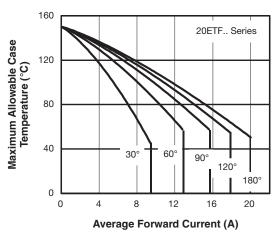


Fig. 1 - Current Rating Characteristics

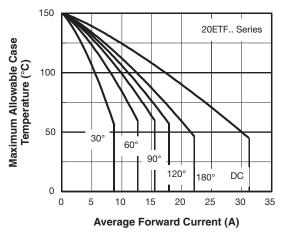


Fig. 2 - Current Rating Characteristics

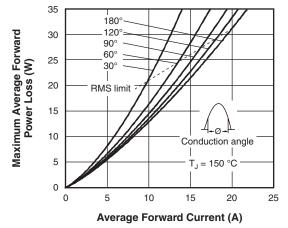


Fig. 3 - Forward Power Loss Characteristics

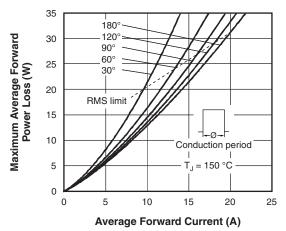


Fig. 4 - Forward Power Loss Characteristics

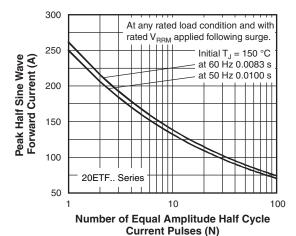


Fig. 5 - Maximum Non-Repetitive Surge Current

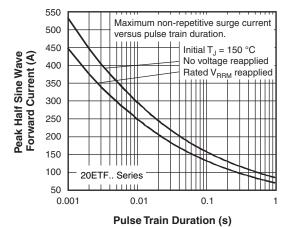


Fig. 6 - Maximum Non-Repetitive Surge Current

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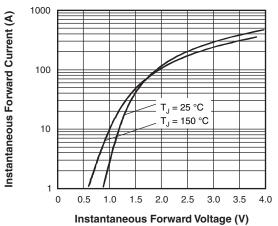
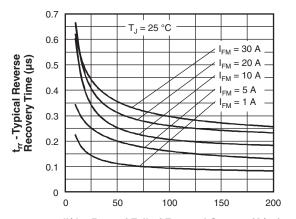


Fig. 7 - Forward Voltage Drop Characteristics



dl/dt - Rate of Fall of Forward Current (A/ μ s) Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

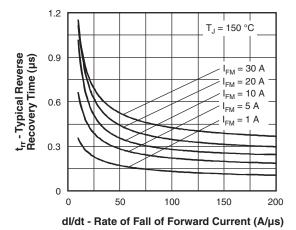
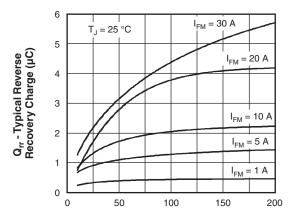
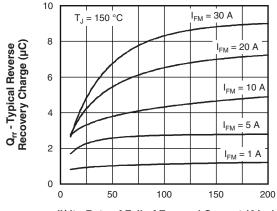


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C



dl/dt - Rate of Fall of Forward Current (A/ μ s) Fig. 10 - Recovery Charge Characteristics, $T_J = 25$ °C



dl/dt - Rate of Fall of Forward Current (A/ μ s) Fig. 11 - Recovery Charge Characteristics, $T_J = 150$ °C



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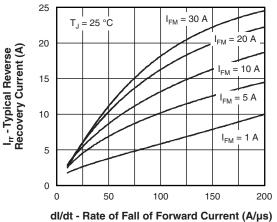
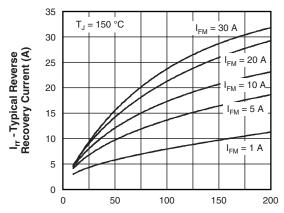


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

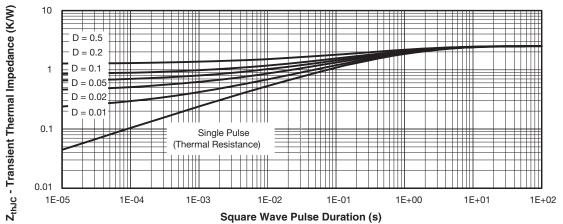
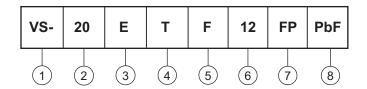


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

3 - Circuit configuration:

E = Single diode

4 - Package:

T = TO-220

5 - Type of silicon:

F = Fast soft recovery rectifier

6 - Voltage code x 100 = V_{RRM} - 10 = 1000 V 12 = 1200 V

7 - FULL-PAK

8 - Environmental digit:

• PbF = Lead (Pb)-free and RoHS compliant

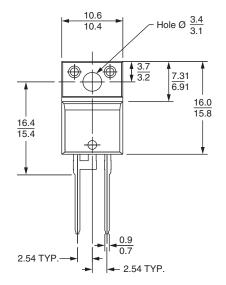
• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

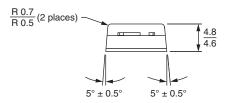
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20ETF10FPPbF	50	1000	Antistatic plastic tubes			
VS-20ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-20ETF12FPPbF	50	1000	Antistatic plastic tubes			
VS-20ETF12FP-M3	50	1000	Antistatic plastic tubes			

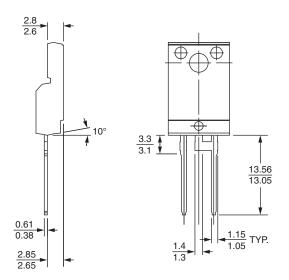
LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95005		
Part marking information	TO-220 FP PbF	www.vishay.com/doc?95009		
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440		

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DIMENSIONS in millimeters







Lead assignments

<u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000

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20ETF10FP 20ETF12FP VS-20ETF12PBF VS-20ETF10PBF VS-20ETF08PBF VS-20ETF12-M3 VS-20ETF10STRRPBF VS-20ETF12FP-M3